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Tailoring bismuth defects in Bi<sub>2</sub>WO<sub>6</sub> nanosheets for photocatalytic C–H activation†Xinye Li,<sup>‡abc</sup> Luteng Luo,<sup>‡a</sup> Hele Guo,<sup>c</sup> Bo Weng,<sup>‡cde</sup> Li Sun,<sup>‡f</sup> Gangamallaiiah Velpula,<sup>‡f</sup> Imran Aslam,<sup>‡c</sup> Maarten B. J. Roeffaers,<sup>‡c</sup> Qinghua Chen,<sup>ab</sup> Lingxing Zeng,<sup>‡\*ab</sup> Min-Quan Yang<sup>‡b</sup> and Qingrong Qian<sup>‡\*ab</sup>

Functionalizing sp<sup>3</sup> C–H bonds in toluene through photocatalysis poses a significant challenge in organic synthesis, garnering substantial research attention. Nevertheless, the inert nature of the C–H bond restricts the photocatalytic conversion efficiency. Here, we construct bismuth defect modified ultrathin Bi<sub>2</sub>WO<sub>6</sub> nanosheets (BT-48) for the conversion of toluene into benzaldehyde under light irradiation. Density functional theory (DFT) calculations validate the effectiveness of Bi defects in Bi<sub>2</sub>WO<sub>6</sub> in activating the C–H bond in toluene. Moreover, a comprehensive physicochemical analysis shows that the introduction of bismuth defects in ultrathin Bi<sub>2</sub>WO<sub>6</sub> nanosheets could promote the separation of photoexcited charge carriers. As a result, the optimal BT-48 sample exhibits an impressive benzaldehyde formation (6781 μmol g<sup>-1</sup> h<sup>-1</sup>) with a high selectivity of 96%, which is 6 times higher than that of Bi<sub>2</sub>WO<sub>6</sub> (1109 μmol g<sup>-1</sup> h<sup>-1</sup>) and surpasses those of all the previously reported Bi<sub>2</sub>WO<sub>6</sub>-based photocatalysts. It is expected that this work could enhance our understanding of designing efficient photocatalysts for the activation of C–H bonds under light illumination.

The activation of the C–H bond, especially the sp<sup>3</sup> C–H bond, stands as a crucial focus within the realm of organic synthesis, which holds immense significance in the synthesis of pharmaceutical intermediates and fine chemicals.<sup>1,2</sup> Nevertheless, traditional C–H bond activation systems commonly face challenges, such as requiring harsh process conditions (high temperature and pressure) and producing hazardous byproducts.<sup>3,4</sup> Consequently, developing efficient and environmentally friendly synthetic protocols for direct activation of the C–H bond has become a crucial facet of green chemistry.<sup>5</sup> Semiconductor-based photocatalytic conversion of the C–H bond, powered by solar energy under mild reaction conditions, has garnered significant interest due to their gentler reaction conditions and potential for sustainability.<sup>6–8</sup>

Among various semiconductors, Bi<sub>2</sub>WO<sub>6</sub> stands out as a promising photocatalyst for C–H activation due to its non-toxic nature, robust oxidation potential, and suitable band gap for solar activation.<sup>9</sup> Numerous Bi<sub>2</sub>WO<sub>6</sub>-based photocatalysts have been developed for activating the sp<sup>3</sup> C–H bond.<sup>10–13</sup> However, the inherent activity of bulk Bi<sub>2</sub>WO<sub>6</sub> is relatively limited due to a scarcity of reactive sites and the rapid recombination of electron–hole pairs.<sup>14,15</sup> Hence, extensive efforts have been dedicated to enhancing the efficiency of C–H bond activation using Bi<sub>2</sub>WO<sub>6</sub> through different methods such as morphology control, introducing co-catalysts, constructing heterostructures, and more.<sup>16–19</sup> For example, Yin *et al.* fabricated flower-like Bi<sub>2</sub>WO<sub>6</sub>, which exhibited improved photocatalytic performance towards selective oxidation of toluene into benzaldehyde as compared to Bi<sub>2</sub>WO<sub>6</sub> nanoparticles.<sup>20</sup> However, the efficiency of Bi<sub>2</sub>WO<sub>6</sub>-based photocatalysts for the C–H bond activation reaction is still unsatisfactory due to the lack of sufficient surface active sites.

Since the C–H bond activation energy can be significantly affected by surface active sites of catalysts, the strategies of nano-architecture aiming at exposing more active sites of Bi<sub>2</sub>WO<sub>6</sub> to promote C–H bond activation are urgently in need.<sup>21</sup> Considering the anisotropic structure and weak interlayer forces of Bi<sub>2</sub>WO<sub>6</sub>, exfoliating bulk structures into ultrathin

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nanosheets with larger specific surface areas and abundant surface atoms can establish reliable active sites.<sup>22</sup> Moreover, engineering defects, including an oxygen vacancy ( $V_O$ ) and/or a Bi vacancy ( $V_{Bi}$ ) of  $Bi_2WO_6$ , within the ultrathin nanosheets can further significantly tailor its electronic state and local coordination environment by regulating the surface atomic structure for promoting C–H bond activation.<sup>23</sup> In general, the presence of  $V_O$  serves to broaden the light response range, whereas  $V_{Bi}$  enhances the adsorption and activation of reactants on the surface. For example, Liu *et al.* demonstrated that the incorporation of  $V_{Bi}$  in  $Bi_2WO_6$  improves the adsorption and mineralization of gaseous toluene.<sup>24</sup> However, it is noteworthy that most studies have primarily concentrated on  $V_O$ , with the engineering of metal Bi vacancies into  $Bi_2WO_6$ , especially for C–H bond activation, being scarcely reported.

Herein, we propose a meticulously optimized defect-doping strategy to construct bismuth defect modified ultrathin  $Bi_2WO_6$  nanosheets (BT-48) for the activation of the  $sp^3$  C–H bond in toluene under light irradiation. The BT-48 catalyst characterized by a blend of theoretical simulations and comprehensive physiochemical analyses could not only enhance the adsorption and activation of the benzylic C–H bond in toluene but also boost the effective desorption of the benzaldehyde product. Additionally, the existence of bismuth defects in  $Bi_2WO_6$  customizes the material's surface electronic structure, thereby promoting the separation and transfer of photogenerated electron-hole pairs while impeding their recombination. Consequently, under simulated solar light irradiation, the benzaldehyde formation rate in toluene employing BT-48 achieves an impressive  $6781 \mu\text{mol g}^{-1} \text{h}^{-1}$  with a high selectivity of 96%, which exhibits a 6-fold improvement compared to that of bulk  $Bi_2WO_6$  ( $1109 \mu\text{mol g}^{-1} \text{h}^{-1}$ ) and surpasses those of all of the previously reported  $Bi_2WO_6$ -based photocatalysts.

Using density functional theory (DFT), we first explore the role of Bi defects in  $Bi_2WO_6$  materials for activation of the  $sp^3$  C–H bond in toluene. We modelled  $Bi_2WO_6$  surfaces with and without bismuth defects, as well as investigated their interaction with toluene. Fig. 1a and b illustrate that the absorption energies of toluene are  $-1.607 \text{ eV}$  for bulk  $Bi_2WO_6$  (denoted as Bulk-BT) and  $-2.174 \text{ eV}$  for the BT-48 sample. The improved absorption energy is ascribed to the presence of Bi defects that strengthen the interaction between the O atom in BT-48 and the H atom from toluene,<sup>25</sup> as supported by the shortened O–H bond length as shown in Fig. S1 (see the ESI† for details). Furthermore, the electron state of toluene experiences significant alteration owing to the intense interaction between BT-48 and toluene (Fig. 1c–f). The C–H bond length of toluene absorbed on BT-48 slightly increases compared to that on Bulk-BT (Fig. S1†). This implies that activating the C–H bond will be easier with the BT-48 sample than with the Bulk-BT material.<sup>26</sup> Additionally, the adsorption energy between the catalyst and product, benzaldehyde, was also evaluated. The absorption energies of benzaldehyde are  $-1.343 \text{ eV}$  and  $-0.646 \text{ eV}$  for Bulk-BT and BT-48 (Fig. S2†), respectively, suggesting that the produced benzaldehyde detaches more easily on the BT-48 surface as compared with Bulk-BT, which is beneficial for enhancing the photocatalytic activity and selectivity of the product.<sup>27</sup> The above calculation results theoretically indicate that, with the introduction of  $V_{Bi}$  defects in  $Bi_2WO_6$  materials, the photocatalytic efficiency of toluene C–H activation can be ultimately improved.

To validate the theoretical predictions, we synthesized a series of Bi defect modified ultrathin  $Bi_2WO_6$  nanosheet materials using acid treatment for different hours ranging from 6 to 72 hours *via* a meticulously optimized hydrothermal method (denoted as BT-*x*, where *x* represents the acid treatment times, and further details are in the ESI†). We select the optimal

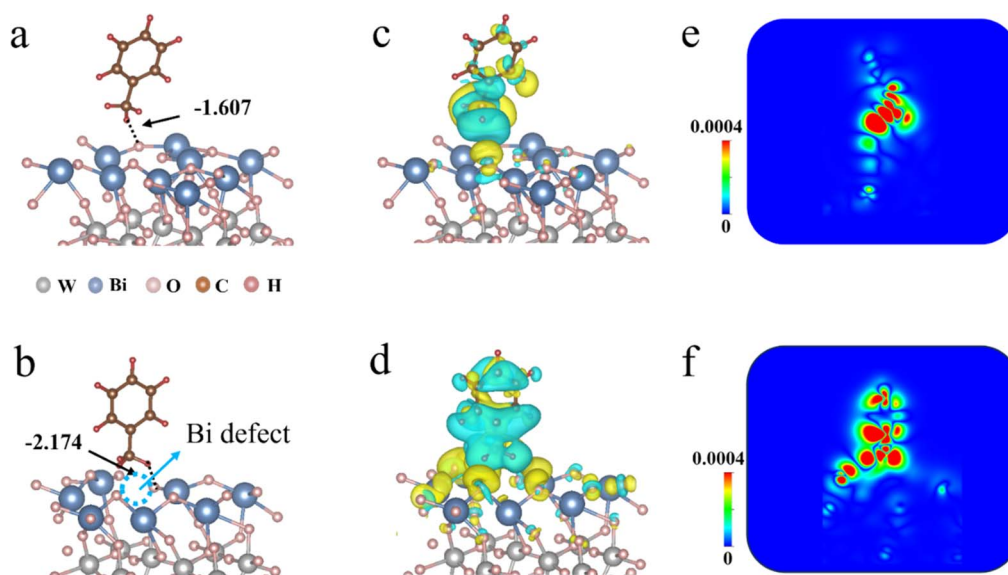


Fig. 1 DFT-derived optimized structures and the adsorption energy of toluene on (a) Bulk-BT and (b) BT-48; differential charge density distribution of toluene adsorbed on (c) Bulk-BT and (d) BT-48; 2D map of differential charge density maps for toluene adsorbed on (e) Bulk-BT and (f) BT-48.



material, BT-48, as a representative sample for analysis. The crystal structure was confirmed through powder X-ray diffraction (XRD) analysis (Fig. S3†), confirming the successful synthesis of  $\text{Bi}_2\text{WO}_6$ .<sup>28</sup> The morphologies of these samples were investigated *via* a scanning electron microscope (SEM). As depicted in Fig. S4,† the morphology of Bulk-BT resembles a flower-like structure composed of nanosheets. Upon subsequent acid treatment, the BT-48 sample maintains its nanosheet morphology, with some thin peeling layers observed on the surface. The transmission electron microscopy (TEM) image in Fig. 2a indicates the nanosheet morphology of the BT-48 sample with a distinct two-dimensional flexible layered structure. EDS (energy dispersive spectroscopy) shows an evenly distributed elemental composition within the BT-48 nanosheets (Fig. S5†). Furthermore, HAADF-STEM (high-angle annular dark-field scanning transmission electron microscopy) in Fig. 2b directly reveals the atomic arrangements of the BT-48 sample with a lattice spacing of 0.27 nm corresponding to the [200] plane of  $\text{Bi}_2\text{WO}_6$ .<sup>29</sup> The relatively heavier Bi makes it appear brighter than W in the dark field.<sup>30</sup> Analyzing atom intensities within the yellow box in the STEM image, the left-most column demonstrates a periodic arrangement of Bi and W atoms, as shown by the purple peaks in Fig. 2c. However, examining the adjacent atom arrays within the same box reveals a conspicuous dip at a Bi site, denoted by the green and blue peaks, which confirms the presence of Bi defects in the BT-48 sample. Additionally, to visually confirm the presence of oxygen vacancies, electron paramagnetic resonance (EPR) spectroscopy was conducted. As shown in Fig. S6,† no typical signal indicating oxygen vacancies at  $g = 2.001$  was observed,<sup>31</sup>

revealing that the primary defect type in BT-48 was isolated bismuth vacancies. Meanwhile, no Bi defects were observed in the HAADF-STEM image of Bulk-BT (Fig. S7†). The atomic force microscope (AFM) results in Fig. 2d and e demonstrate the sheet-like structure of BT-48 with a thickness of approximately 2 to 2.5 nm,<sup>32</sup> indicating its ultrathin nature. Moreover, Fig. S8† shows that the sizes of the Bulk-BT and BT-48 samples are similar.

The Raman spectra in Fig. 2f show robust peaks at 796 and 829  $\text{cm}^{-1}$ , corresponding to the antisymmetric and symmetric Ag stretching modes of terminal O–W–O groups, respectively.<sup>33</sup> An enhanced Raman cross-section for the asymmetric stretching vibration of O–W–O is detected in BT-48 compared to Bulk-BT due to alterations induced by bismuth defects.<sup>34</sup> X-ray photoelectron spectroscopy (XPS) was used to investigate the valence states of various elements (Bi, W and O) in BT-48 and Bulk-BT (Fig. S9†). As shown in Fig. S10,† the high-resolution Bi 4f spectra of BT-48 shift to higher binding energy compared to Bulk-BT, which is attributed to the reduced electron cloud density around  $(\text{Bi}_2\text{O}_2)^{2+}$ .<sup>24,35</sup> Likewise, a similar shift is also observed for the W 4f peaks of BT-48 (Fig. S11†), which is attributed to the formation of bismuth vacancies.<sup>36</sup> The O 1s spectra presented in Fig. S12† indicate a negative shift of the peaks in the BT-48 sample due to the bismuth vacancy-rich configuration.<sup>37</sup> Additionally, the peak area of the O–Bi band in BT-48 is observed to decrease by 30% relative to Bulk-BT, further confirming the presence of bismuth defects.<sup>29,32</sup> To delve deeper into the Bi defects present in BT-48, we conducted an analysis of the atomic concentration ratio of Bi/W, yielding a calculated value of 1.78, which is lower than the theoretical value of 2

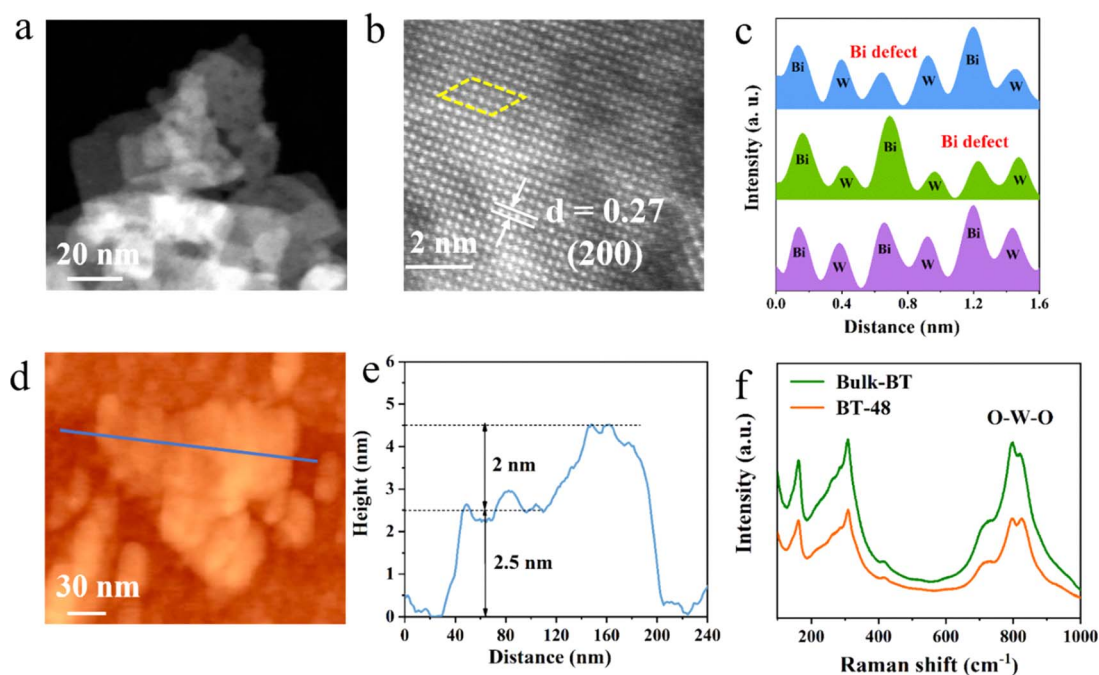


Fig. 2 (a) TEM and (b) HAADF-STEM images of the BT-48 sample, (c) intensity along the blue box indicated in the HAADF-STEM image in panel b, (d) AFM image, (e) the cross-section profiles corresponding to the lines shown in the respective AFM image, and (f) Raman spectra of Bulk-BT and BT-48.



(Table S1†). This finding strongly supports the existence of Bi vacancies in the BT-48 sample, while indicating the absence of Bi defects in the Bulk BT sample.

The light absorption properties of Bulk-BT and BT-48 were investigated by diffuse reflectance spectroscopy (DRS), as depicted in Fig. S13.† The absorption edge of BT-48 shows a slight redshift as compared to Bulk-BT, hinting at a possible improvement in visible light absorption capability and a consequent reduction in the band gap.<sup>38</sup> Calculations based on the formula:  $\alpha h\nu = A(h\nu - E_g)^{1/2}$  (ref. <sup>32</sup>) yield band gap energies of 3.26 eV and 3.21 eV for Bulk-BT and BT-48 samples, respectively. Mott-Schottky analysis in Fig. S14† shows flat band energies of  $-0.92$  eV for Bulk-BT and  $-1.04$  eV for BT-48 samples, which indicates that the conduction band energy values for Bulk-BT and BT-48 are  $-1.02$  and  $-1.14$  eV (*vs.* NHE), respectively. Therefore, the valence band energies for Bulk-BT and BT-48 are determined to be 2.24 eV and 2.07 eV, respectively, as depicted in Fig. S15.† The photocatalytic oxidation of C(sp<sup>3</sup>)-H in toluene to generate benzyl alcohol (BA) and benzaldehyde (BAD) was conducted to evaluate the performance of different samples under simulated solar light irradiation (AM 1.5 G). As illustrated in Fig. 3a, Bulk-BT demonstrates production rates of  $1109 \mu\text{mol g}^{-1} \text{h}^{-1}$  for BAD and  $85 \mu\text{mol g}^{-1} \text{h}^{-1}$  for BA. BT-6 h exhibits significantly increased production rates for BAD ( $3081 \mu\text{mol g}^{-1} \text{h}^{-1}$ ) and BA ( $239 \mu\text{mol g}^{-1} \text{h}^{-1}$ ), indicating that acid treatment enhances the photocatalytic performance of the BT materials. Further prolonging the acid treatment time to 48 h, the optimal BT-48 sample displays the highest photocatalytic activity in toluene oxidation among these materials, boasting production rates of  $6781 \mu\text{mol g}^{-1} \text{h}^{-1}$  for BAD and  $275 \mu\text{mol g}^{-1} \text{h}^{-1}$  for BA. This represents a 6-fold increase compared to the Bulk-BT sample. The catalyst's performance surpasses that of previously reported Bi<sub>2</sub>WO<sub>6</sub>-based catalysts (Fig. 3c and Table S2†).<sup>19,23,24,28,31,32,39-42</sup> Extending the acid treatment to 72 hours leads to reduced BAD and BA production, which is potentially attributed to the damage to the Bi<sub>2</sub>WO<sub>6</sub> structure. Furthermore, the photostability of the BT-48 sample was evaluated by a recycling experiment, as shown in Fig. 3b. No obvious activity loss is observed during five consecutive reaction cycles, demonstrating the excellent photostability of BT-48. The XRD analysis of the BT-48 sample after reactions as shown in

Fig. S16† confirms the high stability and its crystal structure is well-maintained during the photocatalytic reaction process.

To reveal the origin of the photoactivity enhancement in the BT-48 samples compared to Bulk-BT, a series of characterization studies was performed. Nitrogen physisorption (Fig. S17†) revealed that the BT-48 sample exhibits a higher surface area ( $38 \text{ m}^2 \text{ g}^{-1}$ ) compared to Bulk-BT ( $29 \text{ m}^2 \text{ g}^{-1}$ ). This expanded surface area could provide more active sites,<sup>43,44</sup> which potentially enhances the overall photocatalytic activity. Moreover, the photoelectrochemical (PEC) and photoluminescence (PL) spectra of BT-48 and Bulk-BT were recorded to elucidate the charge transfer and charge separation efficiency in these samples. The cyclic voltammetry curves (Fig. S18†), photocurrent (Fig. S19†) and linear sweep voltage (Fig. 4a) indicate faster charge transfer of photogenerated carriers in BT-48 compared to Bulk-BT.<sup>45-47</sup> Electrochemical impedance spectroscopy spectra in Fig. S20† exhibit more efficient charge transfer between the electrode and electrolyte solution in the BT-48 sample than in the Bulk-BT sample.<sup>48,49</sup> Moreover, as shown in Fig. S21,† the PL spectra of these samples exhibit a similar PL emission peak position but with lower intensity for the BT-48 sample, indicating reduced radiative recombination.<sup>50</sup> The density of states (DOS) for BT-48 and Bulk-BT was obtained *via* DFT to investigate the change in the Bi<sub>2</sub>WO<sub>6</sub> electronic band structure induced by Bi defects. Fig. 4c illustrates that introducing Bi defects in BT-48 creates a new impurity state in the gray area, reducing the band gap compared to Bulk-BT (Fig. 4b),<sup>32</sup> consistent with the DRS findings. A new defect level in the forbidden band can be observed relative to Bulk-BT, favoring the electron transition into the conduction band under light irradiation, enabling a higher carrier density and improving electron conductivity.<sup>51</sup> The collective analysis of PEC, PL, and DFT affirms that the Bi defects in BT-48 facilitate the separation and transfer process of photo-generated electron-hole pairs while suppressing their recombination. These factors collectively contribute to promoting the selective oxidation of toluene and enhancing photocatalytic performance.

To further unravel the detailed photocatalytic reaction mechanism, control experiments were conducted with specific radical scavengers, such as ammonium oxalate for holes, potassium persulfate for electrons, 1,4-benzoquinone for  $\cdot\text{O}_2^-$

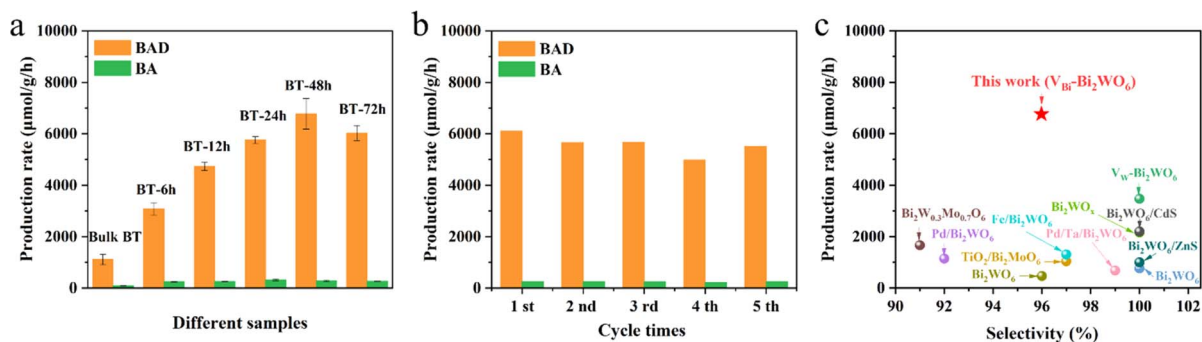


Fig. 3 (a) Photocatalytic oxidation of toluene over samples, (b) recycling tests of toluene oxidation over BT-48, and (c) comparison of the catalytic activity for the benzaldehyde formulation rate over various Bi<sub>2</sub>WO<sub>6</sub>-based photocatalysts. Reaction conditions: photocatalysts (15 mg), Tol (2.5 mL) saturated with O<sub>2</sub>, simulated light irradiation using a 150 W xenon lamp (AM 1.5 G), and irradiation time (4 h).





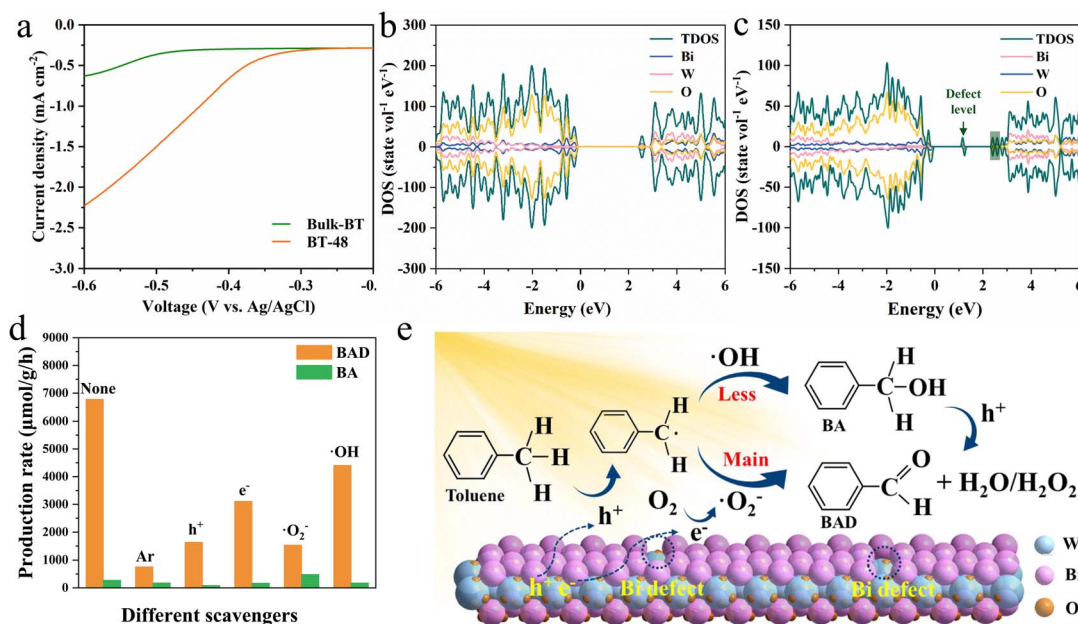


Fig. 4 (a) LSV curves of Bulk-BT and BT-48 samples. The calculated density of states (DOS) of (b) Bulk-BT and (c) BT-48 samples. (d) Toluene oxidation in the absence or presence of various radical scavengers of BT-48. (e) Schematic illustration of the microscopic structure and the mechanism of the photocatalytic reaction and photochromism of BT-48.

and *t*-butanol for OH<sup>-</sup>.<sup>52</sup> Fig. 4d demonstrates that replacing oxygen with argon in the reaction process significantly inhibits toluene oxidation, indicating the crucial role of oxygen in this oxidation process. Moreover, the introduction of hole scavengers into the reaction system reduces BAD formation, highlighting the significant involvement of holes in toluene oxidation. Toluene oxidation is also hindered by the introduction of electron scavengers, but their inhibitory impact on the reaction is less significant compared to that of the hole. Importantly, the yield of BA increases while that of BAD significantly diminishes with the inclusion of O<sub>2</sub><sup>-</sup> scavengers. This could be due to an alternative pathway for BA formation, where O<sub>2</sub><sup>-</sup> radicals are not involved. In contrast, the hindrance to BAD production is lower with the addition of OH scavengers, indicating that the secondary OH-involved pathway is not the primary route for BAD formation. Notably, both the O<sub>2</sub><sup>-</sup> and OH radicals are confirmed by EPR analysis in Fig. S22.†<sup>23,53,54</sup>

Based on the aforementioned data, we propose a photocatalytic mechanism for toluene oxidation over the BT-48 sample. As shown in Fig. 4e, under simulated sunlight illumination, the BT-48 catalyst efficiently generates electron-hole pairs (eqn S1, see the ESI† for details), with the Bi defects in BT-48 facilitating charge carrier separation.<sup>22</sup> Photoexcited holes activate the C-H bond of toluene (eqn S2†), forming toluene radicals and protons.<sup>17</sup> Simultaneously, molecular oxygen adsorbed on the BT-48 surface can be reduced to O<sub>2</sub><sup>-</sup> by electrons (eqn S3†).<sup>55</sup> The produced toluene radicals can react with O<sub>2</sub><sup>-</sup> to yield BAD (eqn S4†), constituting the primary pathway for converting toluene into BAD.<sup>56</sup> Additionally, holes may oxidize with surface-bound H<sub>2</sub>O or OH<sup>-</sup> to generate OH radicals (eqn S5†), further reacting with toluene radicals to produce BA (eqn S6†). Generated BA can then oxidize into BAD facilitated by holes

and OH radicals (eqn S7†).<sup>57</sup> Meanwhile the adsorbed benzylalcohol molecule is activated by a hole to generate the active intermediate of carbon-centered radical, along with the release of a proton (eqn S8†). The O<sub>2</sub><sup>-</sup> radical combines with a proton to form an OOH radical (eqn S9†). Finally, the OOH radical acquires a proton from the carbon centered radical to produce H<sub>2</sub>O<sub>2</sub> and benzaldehyde (eqn S10†).<sup>58</sup> To verify the presence of H<sub>2</sub>O<sub>2</sub>, we probed the production of H<sub>2</sub>O<sub>2</sub> after the photocatalytic oxidation reaction.<sup>59</sup> The findings in Fig. S23† reveal that the H<sub>2</sub>O<sub>2</sub> signal at 325 nm was detected within the reaction system, indicating the coexistence of both mechanisms for aldehyde production from toluene under light irradiation.

In summary, ultrathin Bi<sub>2</sub>WO<sub>6</sub> nanosheets with bismuth defects were engineered to functionalize sp<sup>3</sup> C-H bonds in toluene under simulated solar light irradiation. The optimal BT-48 sample demonstrated a notably higher benzaldehyde production rate (6781 μmol g<sup>-1</sup> h<sup>-1</sup>) than Bulk-BT (1109 μmol g<sup>-1</sup> h<sup>-1</sup>), surpassing the highest performance among reported Bi<sub>2</sub>WO<sub>6</sub>-based photocatalysts for toluene oxidation. Various characterization studies suggest that introducing bismuth defects enhances the activation of C-H bonds in toluene, improves reactant absorption, and facilitates the separation and transfer of photogenerated charge carriers, thus achieving improved photocatalytic performance towards toluene oxidation under light irradiation. These findings are anticipated to deepen our insight into crafting efficient photocatalysts for C-H bond activation.

## Author contributions

X. Li and B. Weng designed the idea. B. Weng, L. Zeng and Q. Qian supervised this study. X. Li, L. Luo, H. Guo, S. Li, G.



Velpulaand and I. Aslam collected and analyzed the data. L. Luo built the structure models. X. Li and L. Luo visualized the results. X. Li, B. Weng, L. Zeng and Q. Qian wrote the draft. M. B. J. Roeffaers, Q. Chen and M. Q. Yang revised the manuscript. All the authors contributed to writing and finalizing the manuscript.

## Conflicts of interest

There are no conflicts to declare.

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